

SANYO Semiconductors DATA SHEET



Monolithic Linear IC — For 1.5V Headphone Stereo Power Amplifier

Features

- Low current drain.
- 16Ω load drive capability.
- Excellent reduced voltage characteristics.
- Excellent power supply ripple rejection.
- Minimum number of external parts required (no input capacitor, feedback capacitor required).
- Less harmonic interference in radio band.
- On-chip power switch function, muting function.

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max	Quiescent	4.5	V
Allowable power dissipation	Pd max		300	mW
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-40 to +125	°C

Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V _{CC}		1.5	V
Operating voltage range	V _{CC} op		0.9 to 4.0	V
Recommended load resistance	RL		16 to 32	Ω

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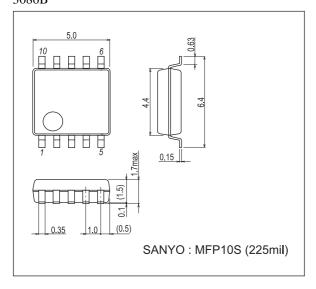
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Parameter	Symbol	Que ditions	Ratings			
		Conditions	min	typ	max	Unit
Quiescent current *1	ICCO1	V_{CC} = 1.2V, quiescent		3.5	6.0	mA
	ICCO ²	$V_{CC} = 2.5V$, pin 10 \rightarrow GND		1.5	2.5	mA
	ICCO3	$V_{CC} = 2.5V$, pin 1 \rightarrow GND			1.0	μA
Voltage gain	VG1	V_{CC} = 1.2V, f = 1kHz, V_{O} = -20dBm	20.5	22	23	dB
	VG2	$V_{CC} = 0.9V$, f = 1kHz, $V_{O} = -20$ dBm	19.5	22	23	dB
Voltage gain difference	ΔVG1	V_{CC} = 1.2V, f = 1kHz, V_{O} = -20dBm			1.0	dB
	ΔVG2	$V_{CC} = 0.9V, f = 1 \text{kHz}, V_{O} = -20 \text{dBm}$			1.0	dB
Total harmonic distortion	THD	$V_{CC} = 1.2V, f = 1kHz, P_{O} = 0.5mW$		0.8	1.5	%
Output power	PO	V _{CC} = 1.5V, f = 1kHz, THD = 10%	5	8		mW
Crosstalk	СТ	V_{CC} = 1.2V, f = 100Hz, Rg = 1k Ω , V_O = -20dB	40	45		dB
Ripple rejection	SVRR	V_{CC} = 1.0V, f = 100Hz, Rg = 1k Ω , V_R = -30dBm, BPF = 100Hz	45	50		dB
Output noise voltage	V _{NO}	V_{CC} = 2.5V, Rg = 1k Ω , BPF= 20Hz to 20kHz		30	44	μV
Power off effect	V _O (off)	V_{CC} = 0.9V, f = 100Hz, pin 1 \rightarrow GND, V_{IN} = -10dB			-80	dBm
Muting effect	V _O (MT)	V_{CC} = 0.9V, f = 100Hz, pin 10 \rightarrow GND, V_{IN} = -10dB			-80	dBm
Power on current sensitivity	l ₁ (on)	$V_{CC} = 0.85V, \ V5 \geq 0.5V$		0.1	1.0	μA
Power off voltage sensitivity	V ₁ (off)	$V_{CC}=0.85V,V5\leq0.1V$	0.5	0.65		V
Muting off current sensitivity	I ₁₀ (off)	$V_{CC} = 0.85V, \ V5 \geq 0.5V$		0.3	1.0	μA
Muting on voltage sensitivity	V ₁₀ (on)	$V_{CC} = 0.85V, V5 \le 0.1V$	0.5	0.65		V

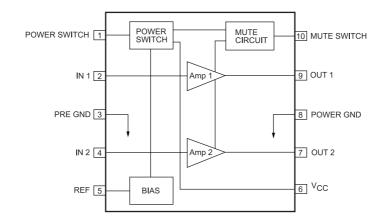
Note) The quiescent current is represented by the current flowing into pin 6. The respective maximum currents flowing into pin 1 and pin 10 are calculated by (V pin -0.5) / 16 [V/ k Ω] and the total current increases by these current values.

Package Dimensions

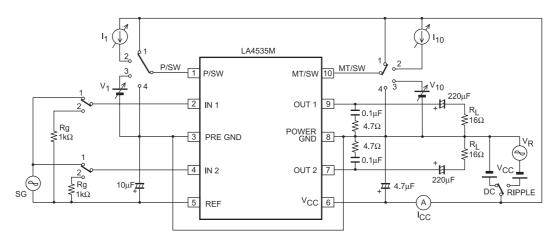
unit : mm (typ) 3086B



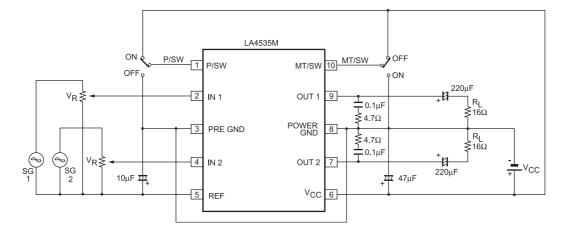
Block Diagram



Test Circuit



Sample Application Circuit



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